



CHENMKO ENTERPRISE CO.,LTD

SURFACE MOUNT
PNP Switching Transistor

VOLTAGE 40 Volts CURRENT 0.2 Ampere

CH3906TGP

Halogens free devices

APPLICATION

- * Telephony and professional communication equipment.
- * Other switching applications.

FEATURE

- * Small surface mounting type. (SC-75/SOT-416)
- * Low current (Max.=200mA).
- * Suitable for high packing density.
- * Low voltage (Max.=40V).
- * High saturation current capability.
- * Voltage controlled small signal switch.

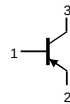
CONSTRUCTION

- * PNP Switching Transistor

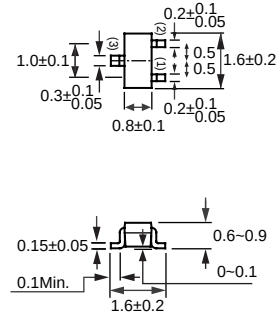
MARKING

- * C

CIRCUIT



SC-75/SOT-416



Dimensions in millimeters

SC-75/SOT-416

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	—	-40	V
V _{CEO}	collector-emitter voltage	open base	—	-40	V
V _{EBO}	emitter-base voltage	open collector	—	-5	V
I _C	collector current DC		—	-200	mA
I _{CM}	peak collector current		—	-200	mA
I _{BM}	peak base current		—	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	—	150	mW
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature		—	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

RATING CHARACTERISTIC CURVES (CH3906TGP)

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	500	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

$T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_{CBO}	collector cut-off current	$I_E = 0; V_{CB} = -30\text{ V}$	–	-50	nA
I_{EBO}	emitter cut-off current	$I_C = 0; V_{EB} = 6\text{ V}$	–	-50	nA
h_{FE}	DC current gain	$V_{CE} = -1\text{ V}$; note 1 $I_C = -0.1\text{ mA}$ $I_C = -1\text{ mA}$ $I_C = -10\text{ mA}$ $I_C = -50\text{ mA}$ $I_C = -100\text{ mA}$	60 80 100 60 30	– – 300 – –	
V_{CEsat}	collector-emitter saturation voltage	$I_C = -10\text{ mA}; I_B = -1\text{ mA}$	–	-250	mV
		$I_C = -50\text{ mA}; I_B = -5\text{ mA}$	–	-400	mV
V_{BEsat}	base-emitter saturation voltage	$I_C = -10\text{ mA}; I_B = -1\text{ mA}$	-650	-850	mV
		$I_C = -50\text{ mA}; I_B = -5\text{ mA}$	–	-950	mV
C_c	collector capacitance	$I_E = I_C = 0; V_{CB} = -5\text{ V}; f = 1\text{ MHz}$	–	4.5	pF
C_e	emitter capacitance	$I_C = I_E = 0; V_{EB} = -500\text{ mV}; f = 1\text{ MHz}$	–	10	pF
f_T	transition frequency	$I_C = 10\text{ mA}; V_{CE} = -20\text{ V}; f = 100\text{ MHz}$	250	–	MHz
F	noise figure	$I_C = 100\text{ }\mu\text{A}; V_{CE} = -5\text{ V}; R_S = 1\text{ k}\Omega; f = 10\text{ Hz to }15.7\text{ kHz}$	–	4	dB

Switching times (between 10% and 90% levels);

t_{on}	turn-on time	$I_{Con} = -10\text{ mA}; I_{Bon} = -1\text{ mA}; I_{Boff} = 1\text{ mA}$	–	65	ns
t_d	delay time		–	35	ns
t_r	rise time		–	35	ns
t_{off}	turn-off time		–	300	ns
t_s	storage time		–	225	ns
t_f	fall time		–	75	ns

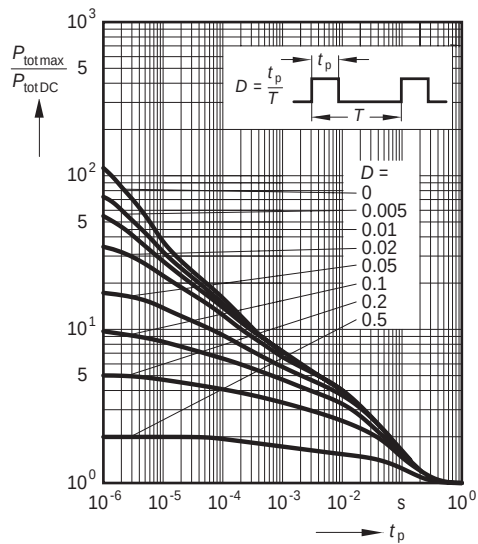
Note

1. Pulse test: $t_p \leq 300\text{ }\mu\text{s}$; $\delta \leq 0.02$.

RATING CHARACTERISTIC CURVES (CH3906TGP)

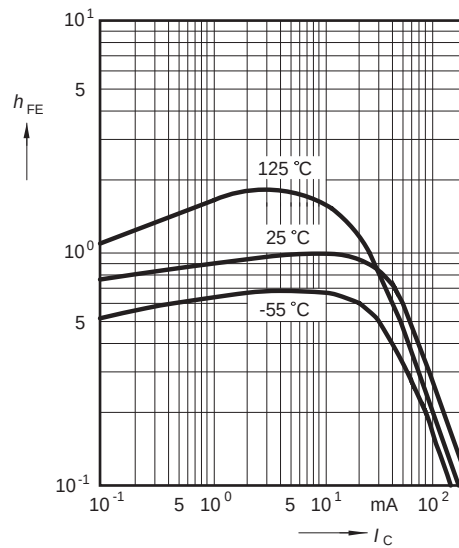
Permissible Pulse Load

$$P_{\text{tot max}}/P_{\text{tot DC}} = f(t_p)$$



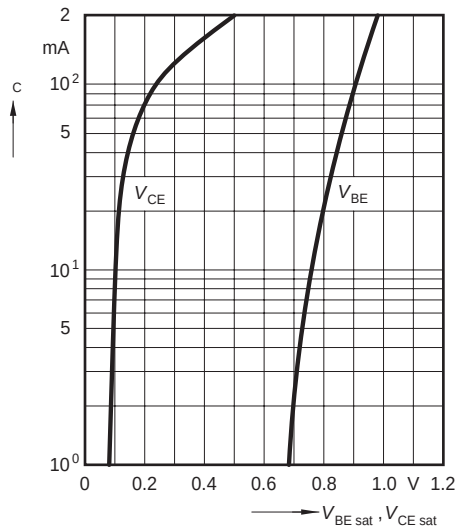
DC current gain $h_{FE} = f(I_C)$

$V_{CE} = 1 \text{ V}$, normalized



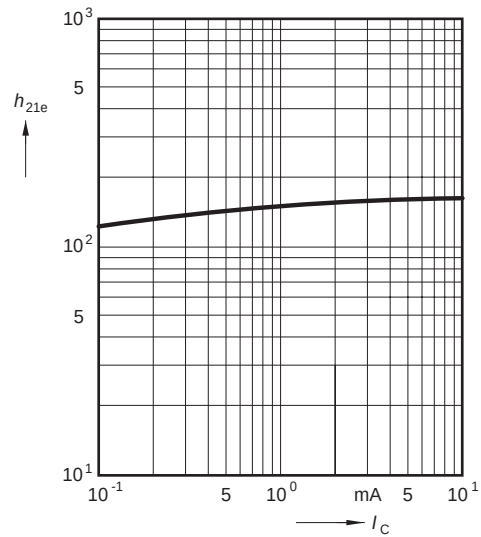
Saturation voltage $I_C = f(V_{BE\text{sat}}, V_{CE\text{sat}})$

$h_{FE} = 10$



Short-circuit forward current transfer ratio $h_{21e} = f(I_C)$

$V_{CE} = 10 \text{ V}$, $f = 1 \text{ MHz}$

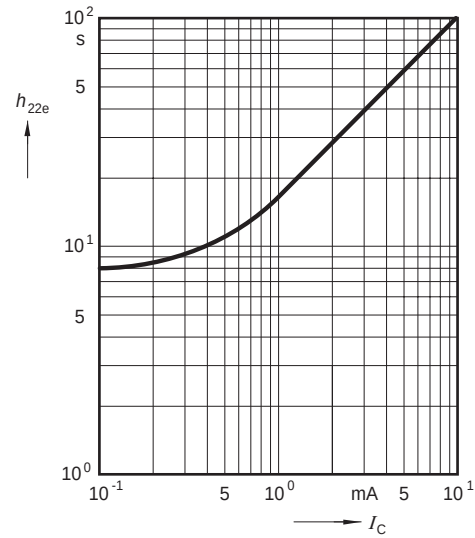


RATING CHARACTERISTIC CURVES (CH3906TGP)

Open-circuit output admittance

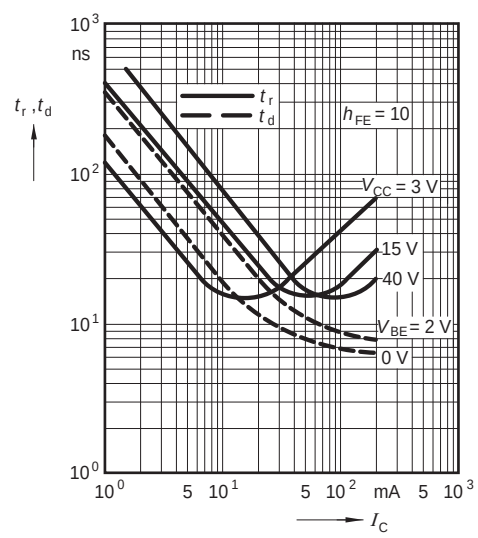
$$h_{22e} = f(I_C)$$

$$V_{CE} = 10V, f = 1MHz$$

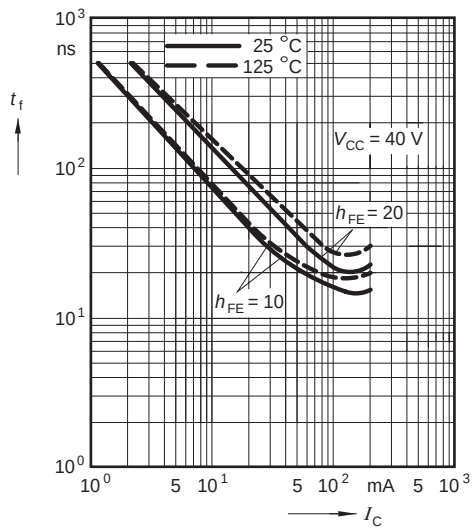


Delay time $t_d = f(I_C)$

Rise time $t_r = f(I_C)$



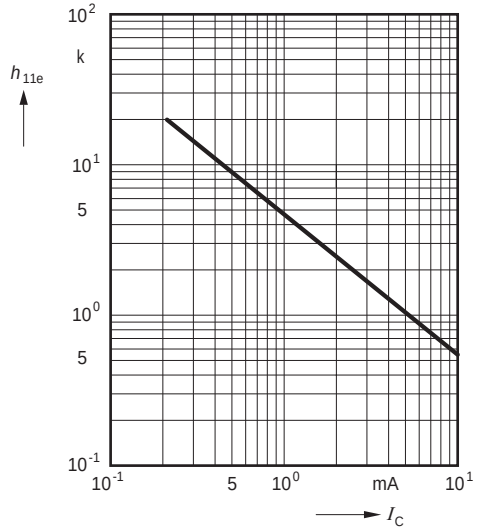
Fall time $t_f = f(I_C)$



Input impedance

$$h_{11e} = f(I_C)$$

$$V_{CE} = 10V, f = 1kHz$$

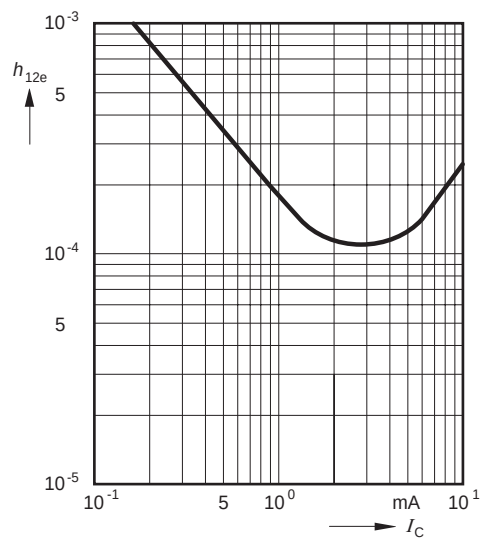


RATING CHARACTERISTIC CURVES (CH3906TGP)

Open-circuit reverse voltage

transfer ratio $h_{12e} = f(I_C)$

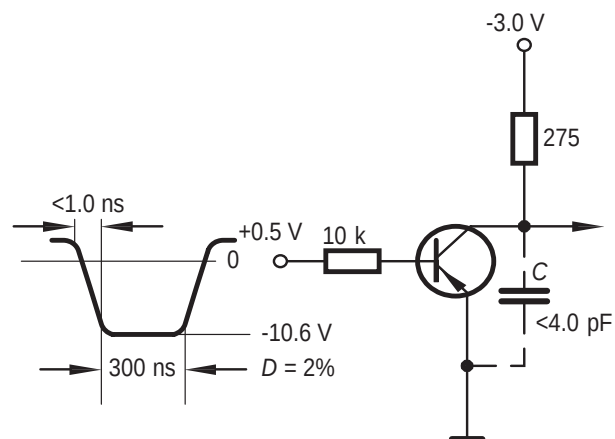
$V_{CE} = 10V, f = 1kHz$



RATING CHARACTERISTIC CURVES (CH3906TGP)

Test circuit

Delay and rise time



Storage and fall time

